PHYSICAL REVIEW B

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(ISSN: 0163-1829)

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THIRD SERIES, VOLUME 57, NUMBER 23 *CONTENTS* 15 JUNE 1998-I

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Analytical expressions for the local-field factor $G(q)$ and the exchange-correlation kernel $K_{xc}(r)$ of the homogeneous electron gas 14 569
Massimiliano Corradini, Rodolfo Del Sole, Giovanni Onida, and Maurizia Palummo

Electron-energy-loss function of $LiTaO_3$ and $LiNbO_3$ by x-ray photoemission spectroscopy: Theory and experiment 14 572
Shigemi Kohiki, Masao Arai, Hideki Yoshikawa, and Sei Fukushima

$NbSe_3$: Effect of uniaxial stress on the threshold field and fermiology 14 576
Jahyong Kuh, Y. T. Tseng, Keith Wagner, Jay Brooks, G. X. Tessema, and M. J. Skove

First-principles study of electric-field gradients at the Cd site for neutral hydrogen-cadmium complexes in crystalline silicon 14 580
M. A. Caravaca, R. A. Casali, and C. O. Rodriguez

Local spin-flip spectral distribution obtained by resonant x-ray Raman scattering 14 584
F. M. F. de Groot, P. Kuiper, and G. A. Sawatzky

Semiconductors I: bulk

Photoluminescence and photoluminescence excitation spectroscopy of multiple Nd^{3+} sites in Nd-implanted GaN 14 588
S. Kim, S. J. Rhee, X. Li, J. J. Coleman, and S. G. Bishop

Phase-correct bond lengths in crystalline Ge_xSi_{1-x} alloys 14 592
J. C. Woicik, K. E. Miyano, C. A. King, R. W. Johnson, J. G. Pellegrino, T.-L. Lee, and Z. H. Lu

Atomic structure of InP(001)-(2×4): A dimer reconstruction 14 596
W. G. Schmidt, F. Bechstedt, N. Esser, M. Pristovsek, Ch. Schultz, and W. Richter

Observation of the conduction-electron spin resonance from metallic antimony-doped silicon 14 600
V. Zarifis and T. G. Castner

Charge redistribution among defects in heavily damaged silicon 14 603
P. K. Giri, Sankar Dhar, V. N. Kulkarni, and Y. N. Mohapatra

Drift mobility of excess carriers in porous silicon 14 607
E. A. Lebedev, E. A. Smorgonskaya, and G. Polisski

Magnetospatial dispersion effect in magnetic semiconductors $Cd_{1-x}Mn_xTe$ 14 611
B. B. Krichevtsov, R. V. Pisarev, A. A. Rzhevsky, V. N. Gridnev, and H.-J. Weber

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Influence of structural disorder on Raman scattering in amorphous porous silicon 14 615
N. N. Ovsyuk and V. N. Novikov

Bond-length variation in $In_xGa_{1-x}As$/InP strained epitaxial layers 14 619
F. Romanato, D. De Salvador, M. Berti, A. Drigo, M. Natali, M. Tormen, G. Rossetto, S. Pascarelli, F. Boscherini, C. Lamberti, and S. Mobilio

Monte Carlo study of Si(111) homoepitaxy 14 623
Makoto Itoh

0163-1829(19980615)57:23;1-Q

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 23** **15 JUNE 1998-I**

Lattice contraction in carbon-doped GaAs epilayers 14 627
Wei Li and Markus Pessa
Electron-phonon scattering in mesoscopic systems 14 630
Andreas Knäbchen
Effective Lagrangian for quantum waveguides 14 634
E. Šimánek
Interplay between the Coulomb blockade and resonant tunneling studied by the Keldysh Green's-function method 14 638
Tetsufumi Tanamoto and Masahito Ueda
Electron energy-loss spectroscopy on the surface of conducting superlattices in the presence of plasma waves 14 642
R. A. Vázquez-Nava, G. H. Cocoletzi, M. del Castillo-Mussot, and W. Luis Mochán

Surface physics, low-dimensional systems, and related topics

Metal segregation and electronic properties of lithium suboxide clusters 14 646
Fabio Finocchi and Claudine Noguera
Effects on the fluid interface fluctuations due to the interaction potential form: Exponential interactions 14 650
George Palasantzas and Godelieve Backx
Surface phase transitions of Ge(100) from temperature-dependent valence-band photoemission 14 654
A. D. Laine, M. DeSeta, C. Cepek, S. Vandré, A. Goldoni, N. Franco, J. Avila, M. C. Asensio, and M. Sancrotti

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Quantum phase transitions of the one-dimensional Peierls-Hubbard model with next-nearest-neighbor hopping integrals 14 658
Hiromi Otsuka
Ground-state properties of rutile: Electron-correlation effects 14 667
Krzysztof Rościszewski, Klaus Doll, Beate Paulus, Peter Fulde, and Hermann Stoll
Electronic topological transitions in Mo-Re random alloys 14 673
N. V. Skorodumova, S. I. Simak, I. A. Abrikosov, B. Johansson, and Yu. Kh. Vekilov
Pressure and magnetic-field effects on charge ordering in $La_{0.9}Sr_{0.1}MnO_3$ 14 680
R. Senis, V. Laukhin, B. Martínez, J. Fontcuberta, X. Obradors, A. A. Arsenov, and Y. M. Mukovskii
Dielectric response functions and Coulomb repulsion parameters in bcc and 9*R* lithium 14 684
Young-Gu Jin and K. J. Chang
Electric-field-gradient calculations using the projector augmented wave method 14 690
Helena M. Petrilli, Peter E. Blöchl, Peter Blaha, and Karlheinz Schwarz
Heat transport in metals irradiated by ultrashort laser pulses 14 698
A. P. Kanavin, I. V. Smetanin, V. A. Isakov, Yu. V. Afanasiev, B. N. Chichkov, B. Wellegehausen, S. Nolte, C. Momma, and A. Tünnermann
Doped antiferromagnets in high dimension 14 704
E. W. Carlson, S. A. Kivelson, Z. Nussinov, and V. J. Emery
Phase diagram of the simplified Hubbard model with a generalized type of hopping in an external magnetic field 14 722
Pavol Farkašovský

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 23** **15 JUNE 1998-I**

Semiconductors I: bulk

Metastability and lattice relaxation for D^0 and D^- donor centers 14 729
S. Bednarek and J. Adamowski

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Surface-core-level-shift low-energy photoelectron diffraction: The 2×1-Si(001) surface 14 739
R. Gunnella, E. L. Bullock, L. Patthey, C. R. Natoli, T. Abukawa, S. Kono, and L. S. O. Johansson
Excitonic properties of ZnSe/(Zn,Mg)Se quantum wells: A model study of the tensile-strain situation 14 749
J. Puls, M. Rabe, A. Siarkos, and F. Henneberger
Fermi surface and electronic structure of Pb/Ge(111) 14 758
A. Mascaraque, J. Avila, E. G. Michel, and M. C. Asensio
Short repulsive binary-alloy chains as a model for disordered quantum wells 14 766
R. Rey-Gonzalez and P. A. Schulz
Crossing of conduction- and valence-subband Landau levels in an inverted HgTe/CdTe quantum well 14 772
M. Schultz, U. Merkt, A. Sonntag, U. Rössler, R. Winkler, T. Colin, P. Helgesen, T. Skauli, and S. Løvold
First-principles optical properties of Si/CaF_2 multiple quantum wells 14 776
Elena Degoli and Stefano Ossicini
Current-density-functional approach to large quantum dots in intense magnetic fields 14 783
M. Pi, M. Barranco, A. Emperador, E. Lipparini, and Ll. Serra
Optical phase conjugation in a single-level metallic quantum well 14 793
Torsten Andersen and Ole Keller
Superfluidity and quantum vortices in systems with pairing of spatially separated electrons and holes in crossed magnetic and electric fields 14 809
S. I. Shevchenko
Remote impurity scattering in modulation-doped GaAs/$Al_xGa_{1-x}As$ heterojunctions 14 813
M. Hayne, A. Usher, J. J. Harris, V. V. Moshchalkov, and C. T. Foxon
Electronic transport and the localization length in the quantum Hall effect 14 818
M. Furlan
Universal scaling and diagonal conductivity in the integral quantum Hall effect 14 829
B. M. Gammel and F. Evers
Accurate effective action for quantum Hall Skyrmions 14 833
Kyungsun Moon and Kieran Mullen
Effect of an ac electric field on chaotic electronic transport in a magnetic superlattice 14 839
Oleg M. Yevtushenko and Klaus Richter
Reflectance anisotropy of silicon surfaces: Discrete dipole calculation 14 843
C. D. Hogan and C. H. Patterson
Inhomogeneous strain relaxation in etched quantum dots and wires: From strain distributions to piezoelectric fields and band-edge profiles 14 850
Y. M. Niquet, C. Priester, C. Gourgon, and H. Mariette
Intensity dependence of superradiant emission from radiatively coupled excitons in multiple-quantum-well Bragg structures 14 860
S. Haas, T. Stroucken, M. Hübner, J. Kuhl, B. Grote, A. Knorr, F. Jahnke, S. W. Koch, R. Hey, and K. Ploog
Ground-state properties and density response of quasi-one-dimensional electron systems 14 869
Daniele Agosti, Francesco Pederiva, Enrico Lipparini, and Kazuo Takayanagi
Optically induced splitting of bright excitonic states in coupled quantum microcavities 14 877
A. Armitage, M. S. Skolnick, V. N. Astratov, D. M. Whittaker, G. Panzarini, L. C. Andreani, T. A. Fisher, J. S. Roberts, A. V. Kavokin, M. A. Kaliteevski, and M. R. Vladimirova

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 57, NUMBER 23** **15 JUNE 1998-I**

In-plane magnetoresistance studies of an extremely coupled double quantum well 14 882
M. A. Blount, J. A. Simmons, and S. K. Lyo

Surface physics, low-dimensional systems, and related topics

Atomic and electronic structures of large and small carbon tori 14 886
V. Meunier, Ph. Lambin, and A. A. Lucas
Quantitative theory of current-induced step bunching on Si(111) 14 891
Da-Jiang Liu and John D. Weeks
Nonlinear optical phenomena on rough surfaces of metal thin films 14 901
Evgeni Y. Poliakov, Vadim A. Markel, Vladimir M. Shalaev, and Robert Botet
Feshbach electron resonances in solid Ar: Opening of electronically inelastic channels 14 914
A. D. Bass, E. Vichnevetski, P. Cloutier, and L. Sanche
Auger, resonant, and plasmon-assisted charge-transfer processes in atom-surface collisions 14 919
M. A. Vicente Alvarez, V. H. Ponce, and E. C. Goldberg
Structure and electronic properties of ordered rare-earth (Ce,Dy)–transition-metal (Pd,Rh) surface compounds 14 930
W. Schneider, S. L. Molodtsov, M. Richter, Th. Gantz, P. Engelmann, and C. Laubschat
Diffraction from two-dimensional vicinal surfaces with noncolliding meandering steps 14 937
Joachim Wollschläger and Mats Larsson
Continuous growth of higher fullerenes through adducting small carbon clusters and annealing 14 950
Yueyuan Xia, Yuguang Mu, Yuelin Xing, Ruijin Wang, Chunyu Tan, and Liangmo Mei
Thermal conductivity and ballistic-phonon transport in the cross-plane direction of superlattices 14 958
G. Chen
Nonlocal density-functional calculations of the surface electronic structure of metals: Application to aluminum and palladium 14 974
M. Heinrichsmeier, A. Fleszar, W. Hanke, and A. G. Eguiluz
Observation and modeling of single-wall carbon nanotube bend junctions 14 983
Jie Han, M. P. Anantram, R. L. Jaffe, J. Kong, and H. Dai
Change of the magnetization reversal mechanism of polycrystalline Ni-Co thin films 14 990
A. Khapikov, L. Uspenskaya, J. Ebothe, and S. Vilain

Errata

Erratum: Generalized gradient approximation for the exchange-correlation hole of a many-electron system [Phys. Rev. B **54**, 16 533 (1996)] 14 999
John P. Perdew, Kieron Burke, and Yue Wang
Erratum: Temperature-dependent Landau damping of the acoustic plasmon in a bilayer system [Phys. Rev. B **57**, 2065 (1998)] 14 999
D. S. Kainth, D. Richards, H. P. Hughes, M. Y. Simmons, and D. A. Ritchie

Cumulative Author Index 15 000